Interfacing Geant4/Garfield++ and Geant4/Degrad
A step by step introduction

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A Geant4/Garfield++ and Geant4/Degrad Interface for the Simulation of Gaseous Detectors

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Contains model verification and source examples, submitted to NIM A: https://arxiv.org/abs/1806.05880
### Task division between Geant4 and Garfield++/Degrad

<table>
<thead>
<tr>
<th>Conduction e- produced by</th>
<th>all</th>
<th>charged particles</th>
<th>photons, gammas</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>A) Geant4</strong></td>
<td>All particles</td>
<td>All charged particles</td>
<td>Gammas, photons</td>
</tr>
<tr>
<td><strong>B) Interface</strong></td>
<td><strong>PAI/PAI photon as additional EM model in gas region</strong></td>
<td>(Relativistic) charged particles</td>
<td><strong>X-rays</strong></td>
</tr>
<tr>
<td><strong>C) Heed</strong></td>
<td><strong>Standard and low energy EM physics</strong></td>
<td><strong>Standard and low energy EM physics</strong></td>
<td><strong>Standard and low energy EM physics</strong></td>
</tr>
<tr>
<td><strong>D) Heed</strong></td>
<td><strong>Kill primary when entering gas</strong></td>
<td><strong>Kill primary when entering gas</strong></td>
<td><strong>Store photon interaction position, kill</strong></td>
</tr>
<tr>
<td><strong>E) Degrad</strong></td>
<td><strong>fStopAndKill status: store e- position</strong></td>
<td><strong>Kill produced secondary e- in gas</strong></td>
<td><strong>Run Degrad to simulate interaction</strong></td>
</tr>
</tbody>
</table>

#### Primary particle
- **Geant4**
  - **PAI/PAI photon as additional EM model in gas region**
  - **fStopAndKill status: store e- position**
- **Garfield++ or Degrad method**
  - **TrackHeed TransportDeltaElectron()**
  - **TrackHeed/SRIM SetParticle() NewTrack()**
  - **TrackHeed TransportPhoton()**
  - **Use conduction electrons from Geant4, Geant4/Heed interface or Heed for Garfield++ simulation according to needs (drift, amplification, signal creation)**
Geant4/Garfield++ interface

include(${Geant4_USE_FILE})
include_directories(${PROJECT_SOURCE_DIR}/include)
include_directories(${ENV{GARFIELD_HOME}/Include})

link_directories(${ENV{GARFIELD_HOME}/Library})
target_link_libraries(IonisationChamber ${
  Geant4_LIBRARIES} -lGarfield -lgfortran)

- Geant4 and Garfield++ are used in the same user C++ program
- Garfield++ includes are added to the CMakeList.txt file
- User program is linked against Geant4 and Garfield++ libraries
**Geant4 parameters: Lower production cut and lowest electron energy**

**Lower production cut:**
Minimum energy transfer required to produce a new particle. If the transferred energy is lower than the lower production cut, the energy is merely recorded as being deposited in the step.

** Lowest electron energy limit:**
Energy threshold below which an electron is not tracked anymore. If the kinetic energy of an electron falls below the lowest electron energy limit value during a step, the full energy deposition independently of material is enforced.

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**PAI model:** Mean number of electron-ion pairs produced by 10 keV electron in a very large volume of He/isoButane 70/30.

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**Variance of electron-ion pair distribution**
Physics list: SetCuts()

```cpp
void UserPhysicsList::SetCuts() {
    /* Geant4 in sequential mode*/
    G4ProductionCutsTable::GetProductionCutsTable()->
    SetEnergyRange(cut*eV, 1.*TeV);
    G4EmParameters* emParams = G4EmParameters::
    Instance();
    emParams->SetLowestElectronEnergy(energy*eV);
}
```

- Lower production cut and lowest electron energy have to be set in SetCut() method of physics list
- If PAI model is used, parameters are of crucial importance to create enough electron-ion pairs
- Deposited energy is not influenced!
- Correct values depend on the gas mixture
- Paper gives guidelines how to determine the correct values
Case A: Geant4 only for creation of electron-ion pairs

```cpp
void GarfieldSeppingAction::UserSteppingAction(const G4Step* theStep) {
    G4Track* track = theStep->GetTrack();
    G4double time = track->GetGlobalTime();
    G4ThreeVector wp = theStep->GetPostStepPoint()->GetPosition();
    G4ThreeVector p = theTouchable->GetHistory()->GetTopTransform().TransformPoint(wp);
    G4String name = track->GetDefinition()->GetParticleName();

    if (name == "e-" && track->GetStatus() == fStopAndKill) {
        /*Send position and time to Garfield++ to continue simulation*/
        SendElectronsToGarfield(p.getX(), p.getY(), p.getZ(), time);
    }
}
```
Performance of different options for creation of electron-ion pairs

<table>
<thead>
<tr>
<th>Physics model in gas region</th>
<th>Simulation time per 1000 events</th>
</tr>
</thead>
<tbody>
<tr>
<td>Geant4 PAI model (case A)</td>
<td>4.14 s</td>
</tr>
<tr>
<td>Geant4/Heed PAI model interface (case B)</td>
<td>2.24 s</td>
</tr>
<tr>
<td>Heed PAI model (case C)</td>
<td>64.20 s</td>
</tr>
</tbody>
</table>

- Comparison of simulation times for $10^5$ 1 GeV electrons in 1 cm of Ar/CO$_2$ 70/30
- Most efficient way of interfacing is to use Geant4 PAI model in conjunction with the Heed PAI model
Case B – D: Heed responsible for creation of electron-ion pairs

```cpp
G4VPhysicalVolume* UserDetectorConstruction::
    Construct() {
    /* Geant4 in sequential mode*/
    G4Region* region = new G4Region("gasRegion");
    region->AddRootLogicalVolume(fLogicalVolumeGas);

    fModel = new GarfieldG4FastSimulationModel("UserModel", region);
}
```

- Geant4 has parametrization feature
- G4VFastSimulationModels can be used as alternative to the Geant4 physics
- Definition of a gas region in which the Garfield FastSimulationModel is used
Case B – D: Heed responsible for creation of electron-ion pairs

- Parameterisation has to be added to physics list
- G4VFastSimulationManagerProcess has to be defined to trigger the FastSimulationModel
- For charged particles, PAI model has to be activated as extra EM model

```cpp
void UserPhysicsList::AddParameterisation() {
  /* Geant4 in sequential mode:
     Create G4FastSimulationManagerProcess*/
  G4FastSimulationManagerProcess* process =
    new G4FastSimulationManagerProcess("G4FSMP");
  auto it = GetParticleIterator();
  it->reset();
  while ((*it)()) {
    G4ParticleDefinition* p = it->value();
    G4ProcessManager* manager = p->GetProcessManager();
    G4EmConfigurator* config = G4LossTableManager::Instance()->EmConfigurator();
    G4String name = "e-";
    if (p->GetParticleName() == name) {
      /*Add G4FastSimulationManagerProcess*/
      manager->AddDiscreteProcess(fastSimProcess);
      /*Add PAI or PAI photon model*/
      G4PAIModel* pai = new G4PAIModel(p, "G4PAIModel");
      config->SetExtraEmModel(name, "eIoni", pai,
                               "gasRegion", 0.*eV, 1.*TeV, pai);
    }
  }
}
```
Definition of FastSimulationModel

class UserFastSimulationModel : public
    G4VFastSimulationModel {

public:
    {/*Constructor and Destructor*/
    UserFastSimulationModel();
    ~UserFastSimulationModel();

    /*virtual methods*/

    /*return true if the G4FastSimulationModel has
to be applied for a particle type*/
    virtual G4bool IsApplicable(const
    G4ParticleDefinition&);

    /*return true if conditions like kinetic
ergy of G4FastTrack are fulfilled*/
    virtual G4bool ModelTrigger(const G4FastTrack &);

    /*The parametrization, i.e. Garfield or Degrad
related code, should be implemented here*/
    virtual void DoIt(const G4FastTrack&,
    G4FastStep&);
};
Definition of FastSimulationModel: 
IsApplicable()

#include "GarfieldG4FastSimulationModel.hh"

G4bool GarfieldG4FastSimulationModel::IsApplicable( 
    const G4ParticleDefinition& particleType) { 
    /*Case B*/
    return &def == G4Electron::ElectronDefinition();

    /*Case C*/
    return &def == G4Proton::ProtonDefinition();

    /*Case D*/
    return &def == G4Gamma::GammaDefinition();

    /*Electroluminescence example*/
    return &def == G4Electron::ElectronDefinition();
}

• The FastSimulationModel is applicable for certain particle types
Definition of FastSimulationModel: ModelTrigger()

```cpp
G4bool GarfieldG4FastSimulationModel::ModelTrigger(
    const G4FastTrack& fastTrack) {
    double ekin = fastTrack.GetPrimaryTrack()->
        GetKineticEnergy() / keV;

    /*Case B*/
    if(ekin < 2. * keV) {return true;}

    /*Case C and D*/
    return true;

    /*Electroluminescence example*/
    if(ekin < 10. * eV) {return true;}

    return false;
}
```

- The FastSimulationModel is triggered at each step for certain particle energies
Definition of FastSimulationModel: DoIt()

```cpp
void GarfieldG4FastSimulationModel::DoIt(const G4FastTrack& fastTrack, G4FastStep& fastStep) {
    /* Get world and local position from fast track, get momentum vector from fast track, get global time in ns, and x,y,z position in cm, get kinetic energy of fast track in eV*/
    double ekin_eV = fastTrack.GetPrimaryTrack()->GetKineticEnergy() / eV;

    /* Kill track in Geant4 - Garfield takes over*/
    fastStep.KillPrimaryTrack();

    /* Number of electrons produced in a collision*/
    int nc = 0;

    Garfield::TrackHeed* trackHeed = new Garfield::TrackHeed();
    trackHeed->EnableDeltaElectronTransport();
}
```

- The primary particle in Geant4 is killed
- Heed track is created
Definition of FastSimulationModel: DoIt()

- For electrons, Heed TransportDeltaElectron is used
- The produced conduction electrons are retrieved
- For charged particles, Heed NewTrack is used
- First the clusters, and then the conduction electrons are retrieved

```cpp
/*Case B*/
trackHeed->TransportDeltaElectron(x_cm, y_cm, z_cm, globaltime, eKin_eV, dx, dy, dz, nc);
for (int cl = 0; cl < nc; cl++) {
    double xe, ye, ze, te;
    double ee, dxe, dye, dze;
    trackHeed->GetElectron(cl, xe, ye, ze, te, ee, dxe, dye, dze);
    /*Garfield++ simulation according to needs*/
}

/*Case C*/
trackHeed->SetParticle("proton");
trackHeed->SetKineticEnergy(eKin_eV);
trackHeed->NewTrack(x_cm, y_cm, z_cm, globaltime, dx, dy, dz);
double xcl, ycl, zcl, tcl, ecl, extra;
while (trackHeed->GetCluster(xcl, ycl, zcl, tcl, nc, ecl, extra)) {
    for (int cl = 0; cl < nc; cl++) {
        double xe, ye, ze, te;
        double ee, dxe, dye, dze;
        trackHeed->GetElectron(cl, xe, ye, ze, te, ee, dxe, dye, dze);
        /*Garfield++ simulation according to needs*/
    }
}
```
Definition of FastSimulationModel: Dolt()

- For photons, Heed TransportPhoton() is used
- The produced conduction electrons are retrieved
- With the conduction electrons, the Garfield++ simulation (drift, avalanches, signal creation) is continued as needed

```c
/*Case D*/
trackHeed->TransportPhoton(x_cm, y_cm, z_cm, globaltime, eKin_eV, dx, dy, dz, nc);
for (int cl = 0; cl < nc; cl++) {
  double xe, ye, ze, te;
  double ee, dxe, dye, dze;
  trackHeed->GetElectron(cl, xe, ye, ze, te, ee, dxe, dye, dze);
  /*Garfield++ simulation according to needs*/
}
```
Geant4/Degrad interface: Electroluminescence example

As before, a FastSimulationModel is defined and attached to a gas region.

The model is applicable for electrons with $E_{\text{kin}} > 7$ eV, produced via the photo-electric effect in Geant4.

Degrad is a Fortran program, the easiest way to execute it is to just run it using the system function.

The Degrad input cards are fed to Degrad using a pipe.

```c
void DegradG4FastSimulationModel::DoIt(const G4FastTrack& fastTrack, G4FastStep& fastStep) {
    //Start by killing the primary track*
    fastStep.KillPrimaryTrack();

    //Store the interaction position and time*/
    G4ThreeVector p = fastTrack.GetPrimaryTrack()->GetVertexPosition();
    G4double t = fastTrack.GetPrimaryTrack()->GetGlobalTime();

    //Generate a random seed to Degrad*/
    G4int n = 54217137*G4UniformRand();
    G4String seed = G4UIcommand::ConvertToString(n);

    // Write the Degrad input cards. Example for photon of 5.9 keV in pure Xenon (thermalization energy of 7.0 eV), in a 3000.0 V/cm electric field anti-parallel to the photon direction. The gas was considered to be at 20 degrees C and 760 Torr. For details see Degrad source file */
    G4String degradCards="printf \"1.1,3,-1,\"+seed+,\n5900.0,7.0,0.0\n7,0,0,0,0,0\n100.0,0.0,0.0,0.0,0.0,0.0,0.0,20.0,760.0\n3000.0,0.0,0.0,1,0\n100.0,0.5,1,1,1,1,1,1,1\n0,0,0,0,0,0" > conditions.txt";
    G4int stdout=system(degradCards.data());

    //Call Degrad with the input conditions file*/
    stdout=system("./degrad < conditions.txt");
```
Geant4/Degrad interface: Electroluminescence example

- Degrad write the position and time of the thermalized electrons to a text file
- Text file is looped through in Geant4
- If position of electron is inside the gas volume (in Degrad the volume is indefinite, hence the check), new secondary electrons are created in Geant4

```cpp
G4ThreeVector ep;
for (int electron=0; electron < NumberOfElectronsProduced; electron++) {
    ep.setX(posXDegrad*0.001+ip.getX());
    ep.setY(posYDegrad*0.001+ip.getY());
    ep.setZ(posZDegrad*0.001+ip.getZ());
    time=timeDegrad*0.001+t;
    /*Check if the electron position is inside the gas volume. Degrad does not use geometrical constraints*/
    G4Navigator* theNavigator = G4TransportationManager::GetTransportationManager()->GetNavigatorForTracking();
    G4VPhysicalVolume* myVolume = theNavigator-> LocateGlobalPointAndSetup(myPoint);
    G4String name=myVolume->GetVolumeName();
    /*gasName should be the name of the gas volume*/
    if (name.contains("gasName")) {
        G4DynamicParticle electron(G4Electron::ElectronDefinition(),G4RandomDirection(), thermalizationEnergy*eV);
        /*Create secondary electron*/
        G4Track *newTrack=fastStep.
        CreateSecondaryTrack(electron, ep,time,false);
        newTrack->SetTrackID(fastStep.
        GetNumberOfSecondaryTracks());
    }
}
```
Garfield++ FastSimulationModel: Electroluminescence example

- Garfield++ FastSimulationModel is valid for electrons with $E_{\text{kin}} < 7$ eV (these electrons were just created in the Degrad FastSimulationModel)
- AvalancheMicroscopic is used to create an electron avalanche
- Callback function is written to access the excitation levels
- Time and position of excitations are stored

```cpp
/*Electroluminescence example: Create the microscopic avalanche class*/
Garfield::AvalancheMicroscopic * aval = new
   Garfield::AvalancheMicroscopic();
/*Connect avalanche microscopic to sensor*/
aval->SetSensor(sensor);
/*Set the callback function*/
aval->SetUserHandleInelastic(
   accessExcitationLevels);
aval->AvalancheElectron(x0,y0,z0,t0,e0,0.,0.,0.);
/*Loop over data structure filled in callback function, produce optical photons in Geant4
}

/*Define a global callback function*/
void accessExcitationLevels(double x, double y, 
   double z, double t, int type, int level,Garfield
   ::Medium * m) {
   /*Access the excitation levels, fill data structure with time and position of excitations*/
}
Garfield++ FastSimulationModel: Electroluminescence example

- At the stored excitation positions, optical photons are produced in Geant4 as secondary particles in the DoIt() method of the FastSimulationModel.
Conclusions

• Geant4/Garfield++ and Geant4/Degrad interface works
• Depending on the use case, different ways exist to interface the Monte Carlo programs
• Paper under review at NIM A
• During work on paper, bugs in Heed C++ implementation detected and corrected
• Possibility to create a Heed like physics process in Geant4 should be investigated Geant4 collaboration to further facilitate the simulations